

VUSG005R30BNA

Datasheet

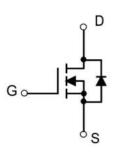
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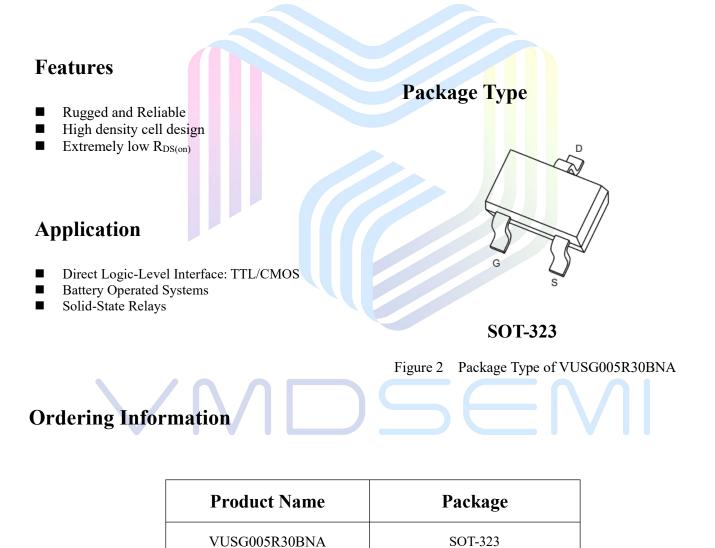
General Description

V _{(BR)DSS}	R _{DS(ON)_max}	I _D
50V	3.0Ω@10V	0.24
	6.0Ω@4.5V	0.34A



Symbol

Figure 1 Symbol of VUSG005R30BNA





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Absolute Maximum Ratings (T_A= 25 °C, unless otherwise specified)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DSS}	50	V
Gate-Source Voltage	V _{GSS}	±20	V
Continuous Drain Current	ID	0.34	A
Total Power Dissipation	PD	0.3	W
Junction Temperature	TJ	150	°C
Storage Temperature	T _{STG}	-55 to 150	°C

Thermal Resistance

Parameter	Symbol	Min	Тур	Max	Unit
Thermal Resistance, Junction-to-Ambient Notel	Røja		4 <mark>17</mark>		°C/W



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Symbol	Test Conditions	Min	Тур	Max	Unit	
Statistic Characteristics						
BV _{DSS}	$V_{GS}=0V, I_{D}=250uA$	50			V	
I _{DSS}	V_{DS} = 50V, V_{GS} =0V			100	nA	
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA	
V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	0.8	1.1	1.5	V	
D	V_{GS} = 10V, I_D = 0.22A		0.8	3.0		
KDS(ON)	V_{GS} = 4.5V, I_D = 0.22A		0.85	6.0	Ω	
g _{FS}	$V_{DS}=10V, I_{D}=0.22A$		0.13		S	
CISS	V _{DS} =25V		26.5		pF	
Coss	V _{GS} =0V		12.9		pF	
C _{RSS}	f=1MHz		5.9		pF	
Switching Parameters						
t _{d(on)}	$V_{DD}=30V$			5		
tr	$V_{GS}=10V$			18		
t _{d(off)}	$I_{\rm D} = 0.29 {\rm A}$			36	ns	
t _f	$R_G=6\Omega$			14		
Source-Drain Diode characteristics ^{Note2}						
V _{SD}	$I_{S}=0.44A, V_{GS}=0V$			1.4	V	
	BV _{DSS} IDSS IGSS VGS(th) RDS(ON) gFS CISS COSS CRSS CRSS td(on) tr td(off) tf	$\begin{tabular}{ c c c c c } \hline V_{DSS} & $V_{GS}=0V$, $I_D=250uA$ \\ \hline I_{DSS} & $V_{DS}=50V$, $V_{GS}=0V$ \\ \hline I_{GSS} & $V_{GS}=\pm20V$, $V_{DS}=0V$ \\ \hline $V_{GS(th)}$ & $V_{DS}=V_{GS}$, $I_D=250uA$ \\ \hline $V_{GS}=10V$, $I_D=0.22A$ \\ \hline $V_{GS}=4.5V$, $I_D=0.22A$ \\ \hline $V_{GS}=4.5V$, $I_D=0.22A$ \\ \hline $V_{DS}=10V$, $I_D=0.22A$ \\ \hline $V_{DS}=10V$, $I_D=0.22A$ \\ \hline $V_{DS}=25V$ \\ \hline C_{OSS} & $V_{GS}=0V$ \\ \hline C_{RSS} & $f=1MHz$ \\ \hline $t_{d(on)}$ & $V_{DD}=30V$ \\ \hline t_r & $V_{GS}=10V$ \\ \hline $t_d(off)$ & $I_D=0.29A$ \\ \hline t_f & $R_G=6\Omega$ \\ \hline \end{tabular}$	$\begin{array}{ c c c c c c } \hline & & & & & & & & & & & & & & & & & & $	$ \begin{array}{ c c c c c c c c c c } & BV_{DSS} & V_{GS} = 0V, I_D = 250uA & 50 & & \\ \hline I_{DSS} & V_{DS} = 50V, V_{GS} = 0V & & & \\ \hline I_{GSS} & V_{GS} = \pm 20V, V_{DS} = 0V & & & \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250uA & 0.8 & 1.1 & \\ \hline V_{GS} = 10V, I_D = 0.22A & 0.8 & \\ \hline V_{GS} = 4.5V, I_D = 0.22A & 0.85 & \\ \hline g_{FS} & V_{DS} = 10V, I_D = 0.22A & 0.13 & \\ \hline \hline C_{ISS} & V_{DS} = 25V & 26.5 & \\ \hline C_{OSS} & V_{GS} = 0V & 12.9 & \\ \hline C_{RSS} & f = 1MHz & 5.9 & \\ \hline t_{d(on)} & V_{DD} = 30V & & \\ \hline t_r & V_{GS} = 10V & I_D & \\ \hline t_{d(off)} & I_D = 0.29A & & \\ \hline t_f & R_G = 6\Omega & & \\ \hline \end{array} $	$\begin{array}{ c c c c c c c c c } BV_{DSS} & V_{GS} = 0V, I_D = 250uA & 50 & & & & & & & & & & & & & & & & & $	

Electrical Characteristics (T_A= 25 °C, unless otherwise specified)

Notes :

1. Device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^{\circ}C$.

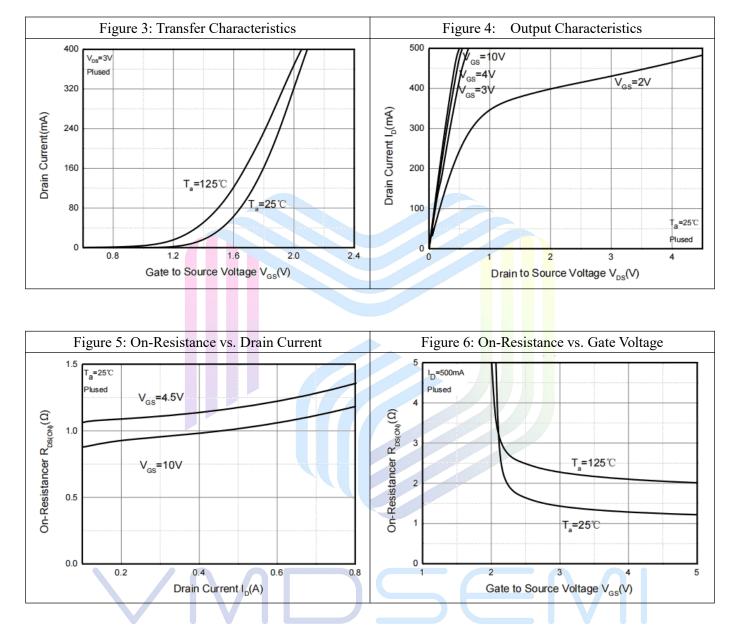
2. Pulse Test ; Pulse Width \leq 300µs, Duty Cycle \leq 2%.

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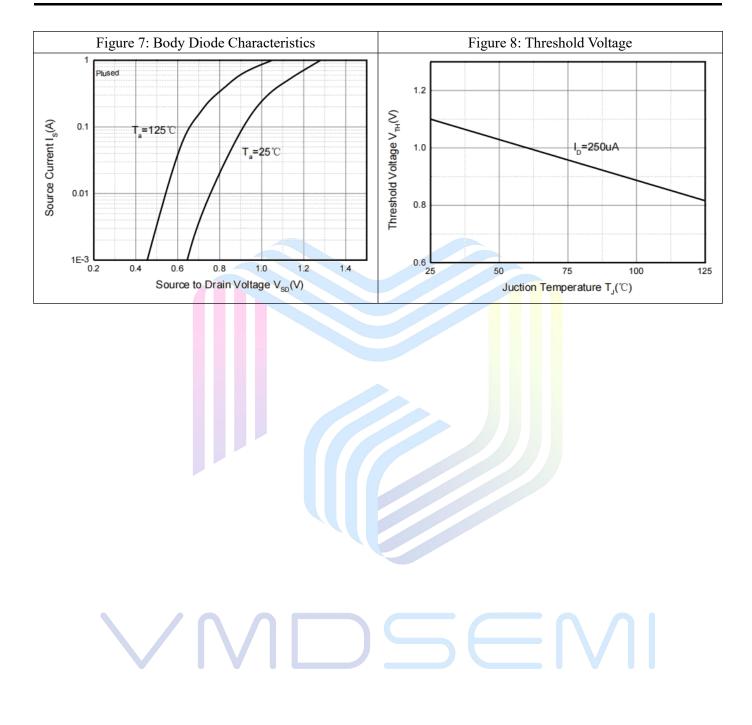
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Typical Performance Characteristics





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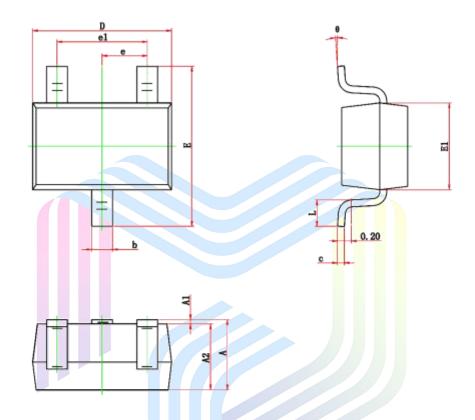




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Mechanical Dimensions:

SOT-323 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.050	0.150	0.002	0.006	
D	1.900	2.200	0.075	0.087	
E	2.000	2.450	0.079	0.096	
E1	1.150	1.350	0.045	0.053	
е	0.650TYP.		0.026	STYP.	
e1	1.200	1.400	0.047	0.055	
L	0.200	0.460	0.008	0.018	
θ	0°	8°	0°	8°	



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